NSN 5962-01-131-7935



Memory Microcircuit - Page 1 of 1	Grou
View Online at https://aerobasegroup.com/nsn/5962-01-131-7935	
Body Length:	
0.840 inches	
Body Width:	
0.310 inches	
Body Height:	
0.175 inches	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and high speed and bipolar and programmable	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
6 input	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
7.0 volts total supply	
Time Rating Per Chacteristic:	
75.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay tin	ne, high to low level
output	
Memory Device Type:	
Prom	
Memory Capacity:	
Unknown	
Terminal Type And Quantity:	
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
-	
Demilitarization:	
Yes - demil/mli	
Fiig:	
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